

View Online at <https://aerobasegroup.com/nsn/5962-00-145-9830>

Body Length:

Between 0.660 inches and 0.785 inches

Body Width:

Between 0.220 inches and 0.280 inches

Body Height:

Between 0.140 inches and 0.180 inches

Maximum Power Dissipation Rating:

440.0 milliwatts

Operating Temperature Range:

-55.0/+125.0 degrees celsius

Storage Temperature Range:

-65.0/+150.0 degrees celsius

Features Provided:

Monolithic and hermetically sealed and positive outputs and high speed and w/buffered output

Inclosure Material:

Ceramic and glass

Inclosure Configuration:

Dual-in-line

Output Logic Form:

Transistor-transistor logic

Input Circuit Pattern:

Dual 4 input

Design Function And Quantity:

2 gate, nand buffer

Case Outline Source And Designator:

T0-116 joint electron device engineering council

Terminal Surface Treatment:

Solder

Voltage Rating And Type Per Characteristic:

-1.5 volts power source and 5.5 volts power source

Time Rating Per Characteristic:

18.00 nanoseconds propagation delay time, low to high level output and 18.00 nanoseconds propagation delay time, high to low level output

Test Data Document:

97942-578r628 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

14 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fig:

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